

## **C100** Consumer Solid State Drive (SSD)

## Introduction

The C100 series solid state drive is developed from years of experience and expertise on storage technology and flash memory management. This product is specialized for optimization of computer operating systems and offers stable and fast data service by accelerating startup and performance.



#### **Available Model**

HS-SSD-C100/120G

HS-SSD-C100/240G

HS-SSD-C100/480G

HS-SSD-C100/960G

HS-SSD-C100/1920G

## **Features and Functions**

High R/W speed

**SATA 3.0** 

Read speed up to 560 MB/s

3D NAND technology

3D NAND offers the potential for higher capacity, performance, and stability

Vibration resistant structure

Free of mechanical structure, electronic chip control for better data safety

Slim and portable

2.5-inch

7 mm thick





# **Specifications**

Model name	HS-SSD-C100						
Capacity	120GB	240GB	480GB	960GB	1920GB		
Size	2.5 inch						
Max Seq read	550MB/s	550MB/s	550MB/s	550MB/s	560MB/s		
MAX Seq Write	420MB/s	450MB/s	470MB/s	480MB/s	520MB/s		
Max. random 4K read IOPS	60K	61K	63K	76K	78K		
Max. random 4K write IOPS	70K	73K	76K	76K	76K		
Power Consumption READ	1.25W	1.34W	1.67W	1.67W	1.67W		
Power Consumption WRITE	1.28W	1.32W	1.64W	1.64W	1.64W		
Power Consumption IDLE	0.3W	0.32W	0.38W	0.38W	0.38W		
Endurance(TBW)	40TB	80TB	160TB	320TB	640TB		
NAND FLASH	3D TLC						
Protocol	SATA 6Gb/s						
Form Factor	2.5 inch SATA						
MTBF (Mean Time between Failures)	2,000,000 hours						
Work Temperature	0-70℃						
Warranty	3 years						
TRIM	yes						

**Note:** Performance test is performed in a specific testing environment and Based on ATTO Disk Bench Mark . Any change of computer system, operation system, hardware, software, or functions will influence the test result.

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